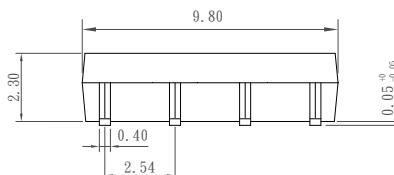
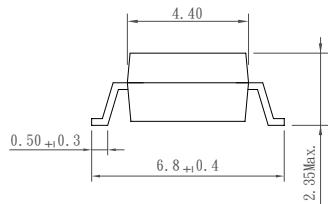
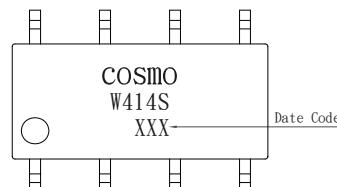
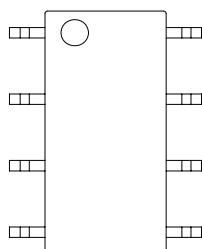


# PRODUCT SPECIFICATION

DATE : 08/20/2012

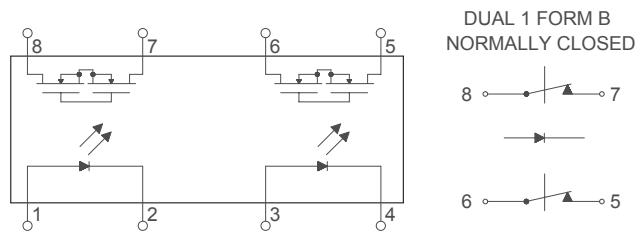
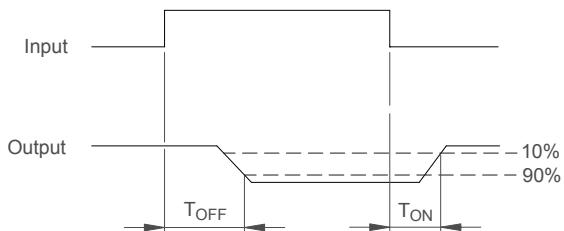
<b>cosmo</b> ELECTRONICS CORPORATION	SOLID STATE RELAY - MOSFET OUTPUT <b>KAQW414S</b>	NO.62M21002	REV. 3
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## ● OUTSIDE DIMENSION :



Unit : mm  
Tolerance :  $\pm 0.2\text{mm}$

## ● Operate / Reverse time



## ● Absolute Maximum Ratings

(Ta=25°C)

Emitter (Input)	Detector (Output)
Reverse Voltage ..... 5.0V	Output Breakdown Voltage ..... $\pm 400\text{V}$
Continuous Forward Current ..... 50mA	Continuous Load Current ..... $\pm 130\text{mA}$
Peak Forward Current ..... 1A	Power Dissipation ..... 500mW
Power Dissipation ..... 100mW	
Derate Linearly from 25°C ..... $1.3\text{mW}/^\circ\text{C}$	

## General Characteristics

Isolation Test Voltage ..... 1500VACrms	Storage Temperature Range ..... -40°C to +125°C
Isolation Resistance ..... $\text{Vio}=500\text{V} , \text{Ta}=25^\circ\text{C}$ ..... $\geq 10^{10}\Omega$	Operating Temperature Range ... -40°C to +85°C
Total Power Dissipation ..... 550mW	Junction Temperature ..... 100°C
Derate Linearly from 25°C ..... $2.5\text{mW}/^\circ\text{C}$	Soldering Temperature , 2mm from case , 10 sec ..... 260°C

# PRODUCT SPECIFICATION

DATE : 08/20/2012

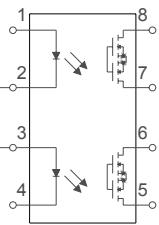
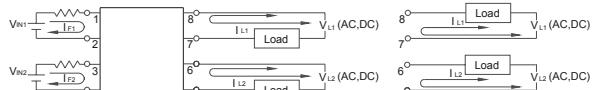
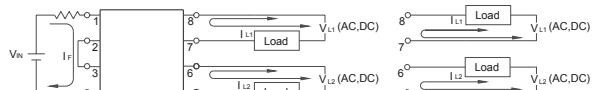
<b>cosmo</b> ELECTRONICS CORPORATION	SOLID STATE RELAY - MOSFET OUTPUT <b>KAQW414S</b>	NO.62M21002	REV. 3
		SHEET 2 OF 7	

## ● Electro-optical Characteristics

( Ta=25°C )

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit.
Emitter ( Input )						
Forward Voltage	$V_F$	$I_F=10\text{mA}$		1.2	1.5	V
Operation Input Current	$I_{F\text{OFF}}$	$V_L=\pm 20\text{V}$ , $I_L \leq 5\mu\text{A}$			5.0	mA
Recovery Input Current	$I_{F\text{ON}}$	$V_L=\pm 20\text{V}$ , $I_L=100\text{mA}$ , $t=10\text{mS}$	0.2			mA
Detector ( Output )						
Output Breakdown Voltage	$V_B$	$I_B=50\mu\text{A}$ , $I_F=10\text{mA}$	400			V
Output Off-State Leakage	$I_{T\text{OFF}}$	$V_T=100\text{V}$ , $I_F=5\text{mA}$		0.2	2	$\mu\text{A}$
I/O Capacitance	$C_{ISO}$	$I_F=0$ , $f=1\text{MHz}$		6		pF
ON Resistance	$R_{ON}$	$I_L=100\text{mA}$ , $I_F=0\text{mA}$		26	50	$\Omega$
Reverse ( ON ) Time	$T_{ON}$	$I_F=10\text{mA}$ , $V_L=\pm 20\text{V}$ $t=10\text{ms}$ , $I_L=\pm 100\text{mA}$		0.6	1.5	ms
Operate ( OFF ) Time	$T_{OFF}$			0.3	1.0	ms

## ● Schematic and Wiring Diagrams

Schematic	Output Configuration	Load	Connection	Wiring Diagrams
	2b	AC/DC	-	<p>( 1 ) Two Independent 1 Form B use</p>  <p>( 2 ) 2 Form B use</p> 

# PRODUCT SPECIFICATION

DATE : 08/20/2012

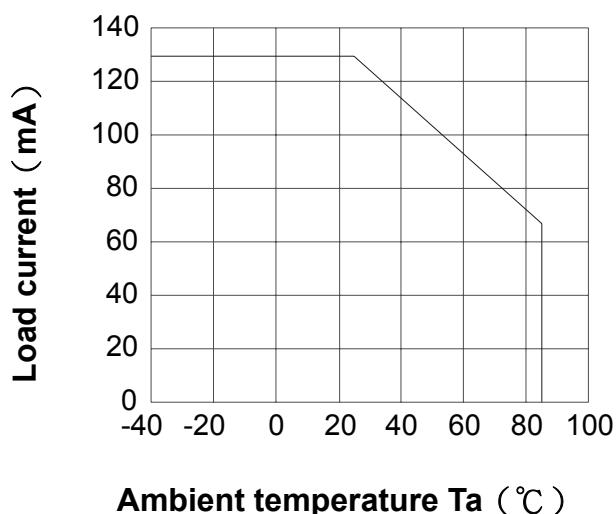
<b>cosmo</b> ELECTRONICS CORPORATION	SOLID STATE RELAY - MOSFET OUTPUT <b>KAQW414S</b>	NO.62M21002	REV. 3
		SHEET 3 OF 7	

## ● Data Curve

Load current vs. ambient temperature

Allowable ambient Temperature :

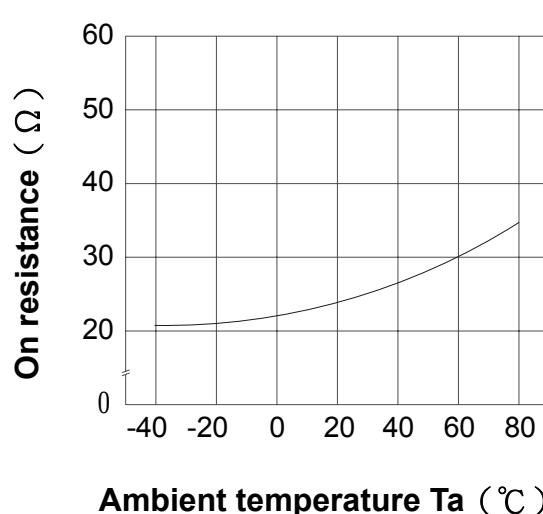
-40°C to +85°C



On resistance vs. ambient temperature across terminals 5,7 and 6,8 pin

LED current : 5mA

Continuous load current : 130mA (DC)



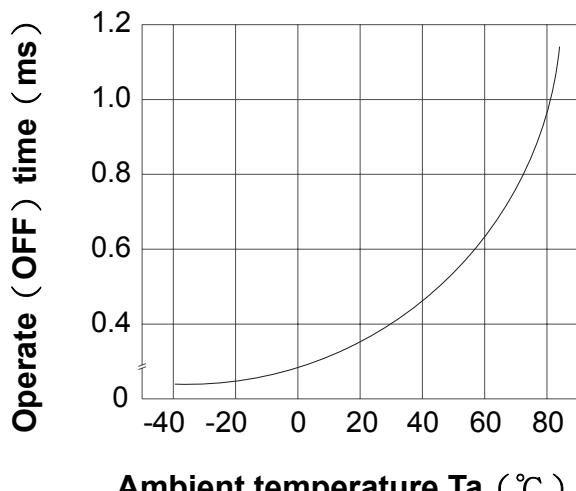
Operate (OFF) time vs.

ambient temperature

Load voltage 400V (DC)

LED current : 5mA

Continuous load current : 130mA (DC)



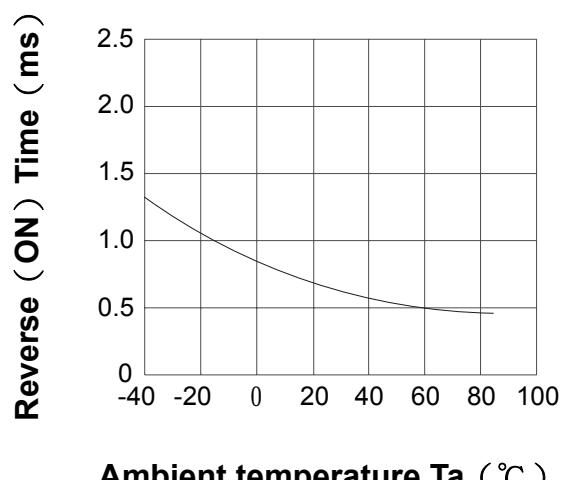
Reverse (ON) time vs.

ambient temperature

Load voltage 400V (DC)

LED current : 5mA

Continuous load current : 130mA (DC)

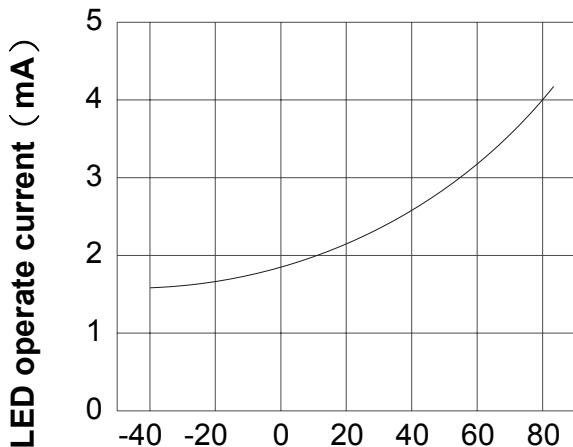


# PRODUCT SPECIFICATION

DATE : 08/20/2012

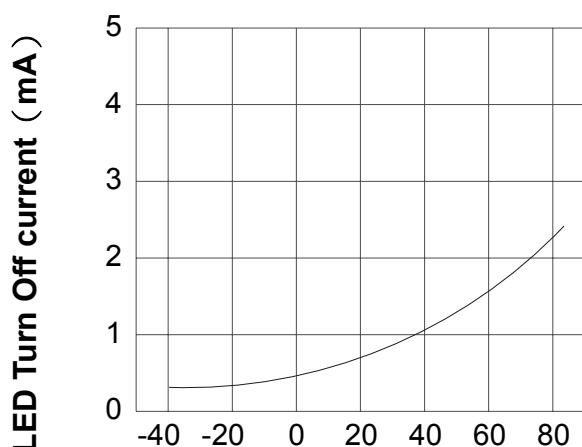
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		SHEET 4 OF 7	

LED operate current vs.  
ambient temperature  
Load Voltage : 400V (DC)  
Continuous load current : 130mA (DC)



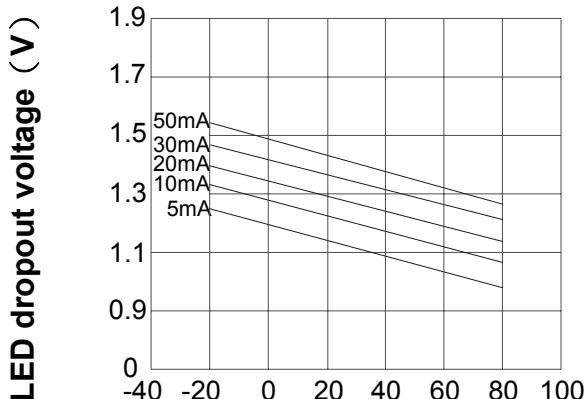
Ambient temperature Ta (°C)

LED Turn Off current vs.  
ambient temperature  
Load Voltage : 400V (DC)  
Continuous load current : 130mA (DC)



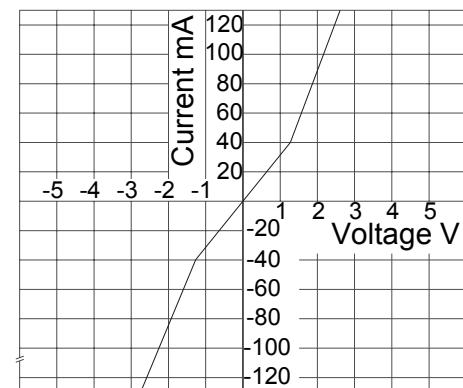
Ambient temperature Ta (°C)

LED dropout voltage vs.  
ambient temperature  
LED current : 5 to 50mA



Ambient temperature Ta (°C)

Voltage vs. current characteristics  
of output at MOSFET portion  
Measured portion : across terminals  
5,7 and 6,8 pin  
Ambient temperature : 25°C



Ambient temperature : 25°C

# PRODUCT SPECIFICATION

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<b>cosmo</b> ELECTRONICS CORPORATION	SOLID STATE RELAY - MOSFET OUTPUT <b>KAQW414S</b>	NO.62M21002	REV. 3
		SHEET 5 OF 7	

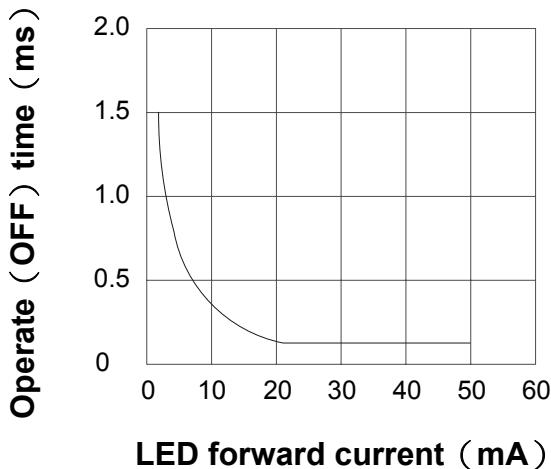
## LED forward current vs. Operate (OFF) time

Across terminals 5,7 and 6,8 pin

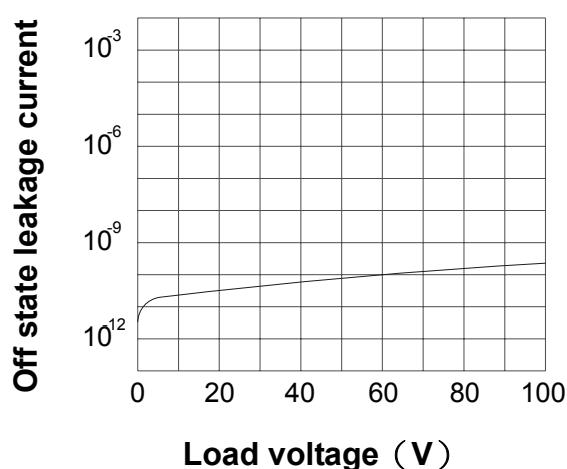
Load voltage : 400V (DC)

Continuous load current : 130mA (DC)

Ambient temperature : 25°C



Off state leakage current  
Across terminals 5,7 and 6,8 pin  
Ambient temperature : 25°C



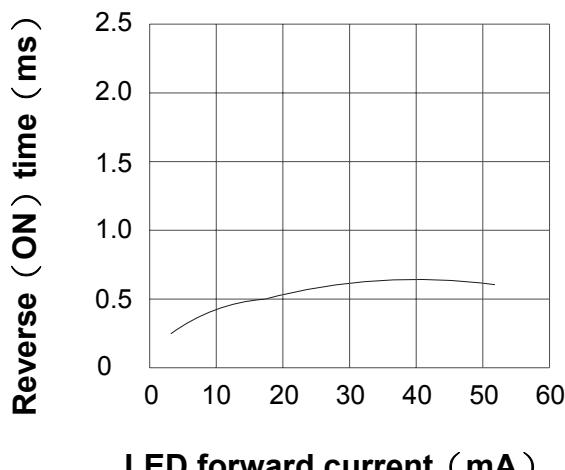
## LED forward current vs. reverse (ON) time

Across terminals 5,7 and 6,8 pin

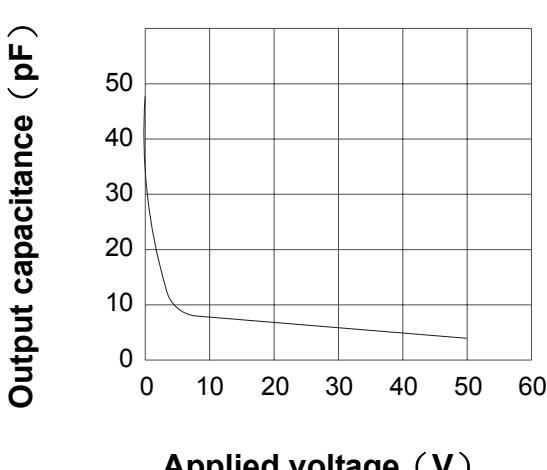
Load voltage : 400V (DC)

Continuous load current : 130mA (DC)

Ambient temperature : 25°C



Applied voltage vs. output capacitance  
Across terminals 5,7 and 6,8 pin  
Frequency : 1MHz  
Ambient temperature : 25°C



# PRODUCT SPECIFICATION

DATE : 08/20/2012

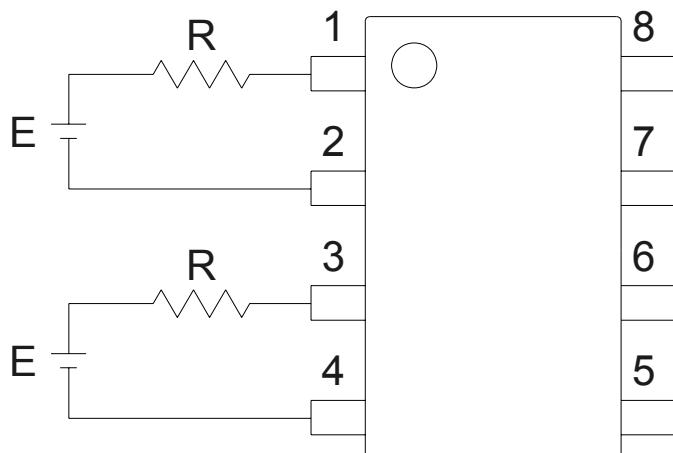
<b>cosmo</b> ELECTRONICS CORPORATION	SOLID STATE RELAY - MOSFET OUTPUT <b>KAQW414S</b>	NO.62M21002	REV. 3
		SHEET 6 OF 7	

## ● USING METHODS

Examples of resistance value to control LED forward current (IF)

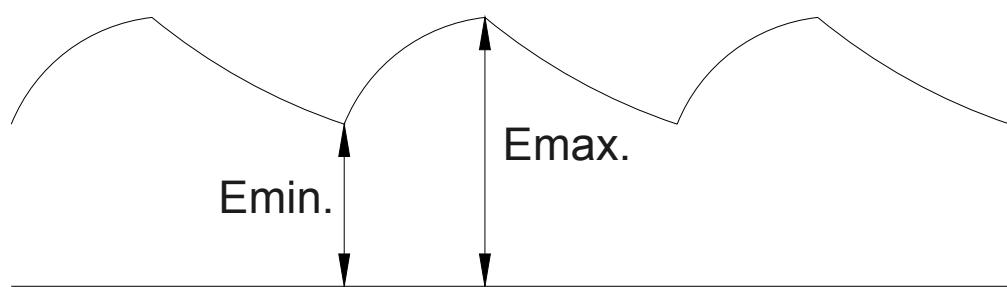
SSR-MOSFET OUTPUT

( IF=5mA )



E	R
3.3V	Approx. 330 Ω
5V	Approx. 640 Ω
12V	Approx. 1.9K Ω
15V	Approx. 2.5K Ω
24V	Approx. 4.1K Ω

- (1) LED forward current must be more than 5mA , at E min.
- (2) LED forward current must be less than 50mA , at E max.



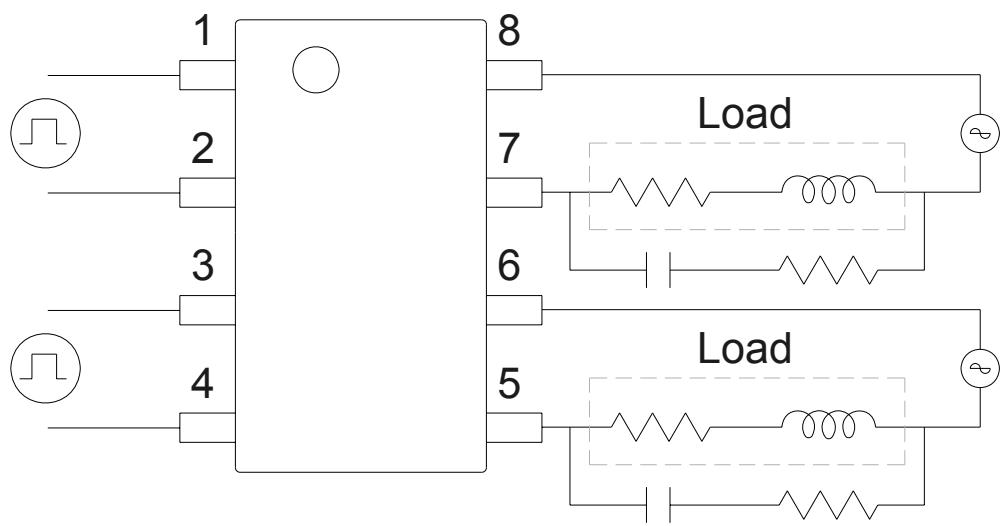
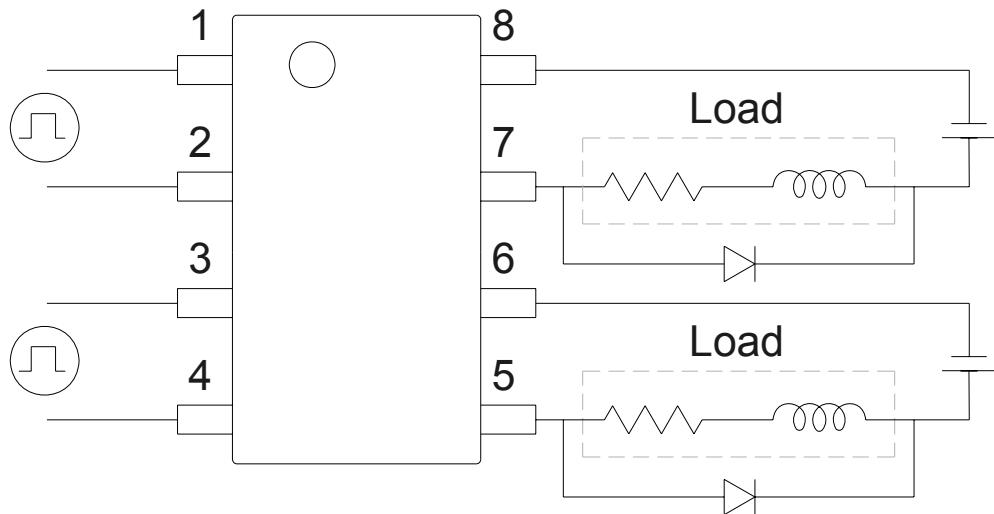
# PRODUCT SPECIFICATION

DATE : 08/20/2012

<b>cosmo</b> ELECTRONICS CORPORATION	SOLID STATE RELAY - MOSFET OUTPUT <b>KAQW414S</b>	NO.62M21002	REV. 3
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## ● USING METHODS

Regulate the spike voltage generated on the inductive load as follows :



R-C Snubber